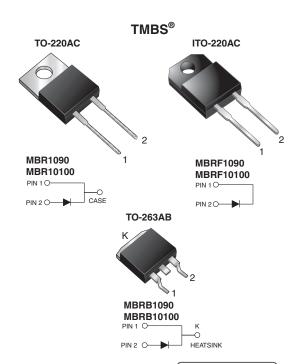


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High Voltage Trench MOS Barrier Schottky Rectifier



DESIGN SUPPORT TOOLS

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PRIMARY CHARACTERISTICS						
I _{F(AV)}	10 A					
V_{RRM}	90 V, 100 V					
I _{FSM}	150 A					
V _F	0.65 V					
T _J max.	150 °C					
Package	TO-220AC, ITO-220AC, D ² PAK (TO-263AB)					
Circuit configuration	Single					

FEATURES

- Trench MOS Schottky technology
- · Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AC and ITO-220AC package)
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters or polarity protection application.

MECHANICAL DATA

Case: TO-220AC, ITO-220AC, D2PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR1090 MBR101		100 UNIT	
Maximum repetitive peak reverse voltage	V_{RRM}	90	100	V	
Working peak reverse voltage	V _{RWM}	90	100	V	
Maximum DC blocking voltage	V_{DC}	90	100	V	
Maximum average forward rectified current at T _C = 133 °C	I _{F(AV)}	10		А	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	150		А	
Non-repetitive avalanche energy at T _J = 25 °C, L = 60 mH	E _{AS}	130		mJ	
Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, T_J = 38 °C \pm 2 °C per diode	I _{RRM}	0.5		А	
Voltage rate of change (rated V _R)	dV/dt	10 000		V/µs	
Isolation voltage (ITO-220AC only) from terminal to heatsink t = 1 min	V _{AC}	1500		V	
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +150		°C	

MBR10xxx-E3, MBRF10xxx-E3, MBRB10xxx-E3

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	MAX.	UNIT	
Maximum instantaneous forward voltage	I _F = 10 A	T _C = 25 °C	V _F ⁽¹⁾	0.80	V	
	I _F = 10 A	T _C = 125 °C		0.65		
	I _F = 20 A	T _C = 125 °C		0.75		
Maximum reverse current per at working peak		T _J = 25 °C	1 (2)	100	μΑ	
reverse voltage		T _J = 125 °C	- I _R ⁽²⁾	6.0	mA	

Notes

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT	
Typical thermal resistance	$R_{\theta JA}$	60	-	60	°C/W	
	$R_{ heta JC}$	2.0	3.5	2.0	C/VV	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AC	MBR10100-E3/4W	1.845	4W	50/tube	Tube		
ITO-220AC	MBRF10100-E3/4W	1.661	4W	50/tube	Tube		
TO-263AB	MBRB10100-E3/4W	1.384	4W	50/tube	Tube		
TO-263AB	MBRB10100-E3/8W	1.384	8W	800/reel	Tape and reel		

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

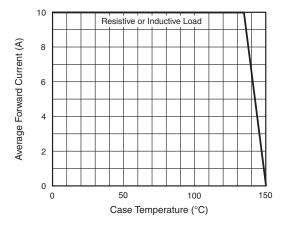


Fig. 1 - Forward Current Derating Curve

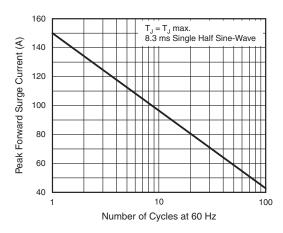


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

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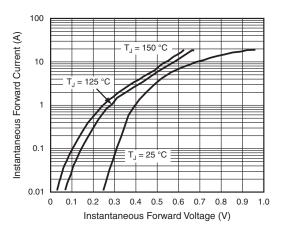


Fig. 3 - Typical Instantaneous Forward Characteristics

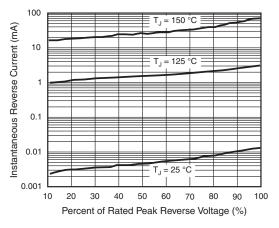


Fig. 4 - Typical Reverse Characteristics

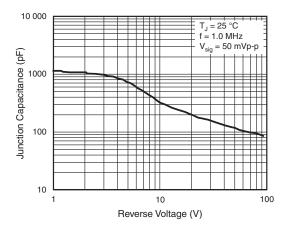


Fig. 5 - Typical Junction Capacitance

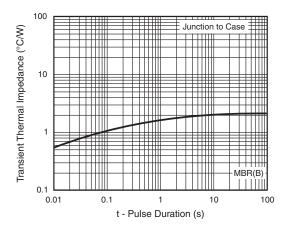


Fig. 6 - Typical Transient Thermal Impedance

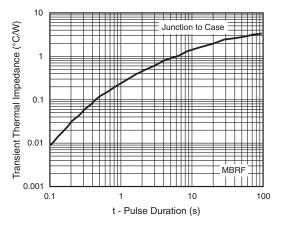


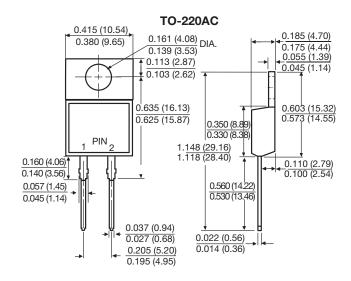
Fig. 7 - Typical Transient Thermal Impedance

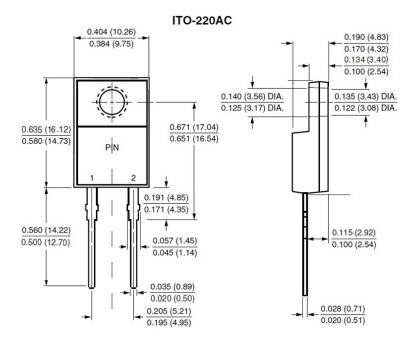


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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





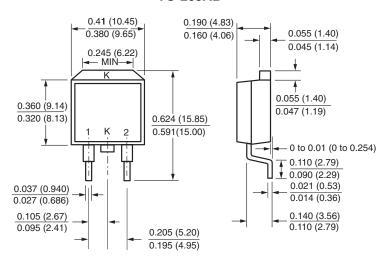


MBR10xxx-E3, MBRF10xxx-E3, MBRB10xxx-E3

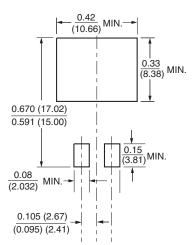
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TO-263AB



Mounting Pad Layout





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